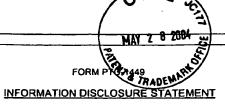
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104	AA1	US 2002/0130311	09/2002	Lieber et al.					
TA	AB1	US 2002/0130353	09/2002	Lieber et al.					
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	AL1						Yes No		
	AM1						Yes No		
	AN1						Yes No		
	AO1						Yes No		
	AP1						Yes No		
		OTHER (II	ncluding Autho	or, Title, Date, Pertinent P	ages, etc.)	·			
TA	AR	Chung et al 2000, 5 pgs	Chung et al., "Silicon nanowire devices", American Institute of Physics, Vol. 76, No. 15, April 10, 2000, 5 pgs.						
IA	AS		Duan et al., "High-performance thin-film transistors using semiconductor nanowires and nanoribbons", Nature, Vol. 425, September 18, 2003, pgs. 274-278						
14	AT	Toshishige Physics Let	Toshishige Yamada, "Analysis of submicron carbon nanotube field-effect transistors", Applied Physics Letters, Vol. 76, No. 5, January 31, 2000, American Institute of Physics, 5 pgs.						
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	AO2						]	Yes No
	AP2							Yes No
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M	Tans et al., "Room-temperature transistor based on a single carbon nanotube", Nature, Vol. 393, Ma 7, 1998, 5 pgs.							, Vol. 393, May
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